

## STRUCTURAL, ELECTRICAL AND OPTICAL PROPERTIES OF NANOCRYSTALLINE PbS THIN FILMS

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### ABSTRACT

We report the synthesis, microstructural, optical and electrical properties of nanocrystalline lead sulphide thin films grown on glass substrates by using sol gel spin coating techniques. The XRD and SEM measurements confirmed that the thin films grown by this technique have good crystalline cubic structures and homogeneous surfaces. The dc electrical conductivity found in the range of  $10^{-5}$  to  $10^{-6}$  ( $\Omega \text{ cm}$ )<sup>-1</sup>. The optical studies revealed that the high absorption coefficient ( $\approx 10^4 \text{ cm}^{-1}$ ) with direct energy gap of 0.41 eV.

**KEY WORDS:** PbS, SEM, sol gel method, spin coating technique, XRD

### INTRODUCTION

Nanometer sized semiconductor particles have attracted much attention over the past few years because of their novel electrical and optical properties originating from quantum confinement. The emphasis has been mainly given on the synthesis of semiconductor particles belonging to II-VI and III-V groups, which show significant quantum confinement effects. Semiconductor nanoparticles exhibit size –dependent electronic band gap energies (Brus, 1994), melting temperatures (Goldstein *et al.*, 1992), solid state phase transition temperatures (Qadri *et al.*, 1999) and pressures (Chen *et al.*, 1997). In addition to these, doped semiconductor nanoparticles have tremendous potential for use in light emitting applications. For examples PbS is an important material for a variety of applications such as, electroluminescent devices, solar cells, gas sensors and other optoelectronic devices. Hence, there has been growing interest in developing techniques for preparing semiconductor nanoparticle films. The sol gel synthesis method is simple and inexpensive alternative to more complex physical and chemical vapour deposition. The physical methods (Alivisatos, 1998), that are commonly used for the fabrication of low dimensional solids have some resolution limits that restrict these techniques from reaching to nanometer scale. On the other hand, colloid chemistry route offers a simple means to synthesize such particles with good control of size and size distribution. In the past few years there have been various reports of synthesizing nanometersized PbS (Nanda *et al.*, 2000; Bhattacharjee *et al.*, 2002) particles by chemical process using suitable capping or surface passivating agents to control the size of the particles. This paper reports on investigations of structural, morphological, electrical and optical properties of nanocrystalline PbS by sol gel spin coating technique first time.

### MATERIALS AND METHODS

#### Experimental

Present study, synthesized nanocrystalline PbS by sol gel method without using any capping agent. To prepare nanocrystalline PbS powders, we have taken two types of solution. Solution –I was prepared by dissolving lead acetate in 40 ml methanol. In solution II, thiourea was dissolved in 40 ml methanol. Solution II was added to the solution I drop wise. The mixed solution was stirred, heated at 60 °C for about 1 hrs. After 1 hrs the dark chocolate color powder of PbS is formed. The powder was thoroughly washed several times with methanol and then dried in vacuum. The PbS powder was annealed at different temperatures (100, 200, 300 °C).

To prepare thin films, 1 gm of annealed PbS nanopowder was mixed with 24 ml of m-cresol. Thin films were deposited on glass substrates using spin coating technique. The structural properties of nanocrystalline PbS was studied by X-ray diffraction (XRD) (Philips PW3710, Holland) using filtered CuK $\alpha$  radiation ( $\lambda=1.5406 \text{ \AA}$ ). The surface morphologies of the PbS thin films were observed by scanning electron microscope JEOL JSM 6360 operating at 20 kV.

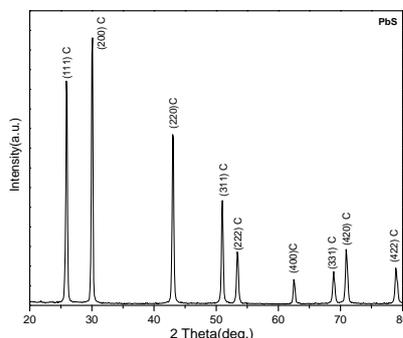
### RESULTS AND DISCUSSION

#### X ray diffraction studies

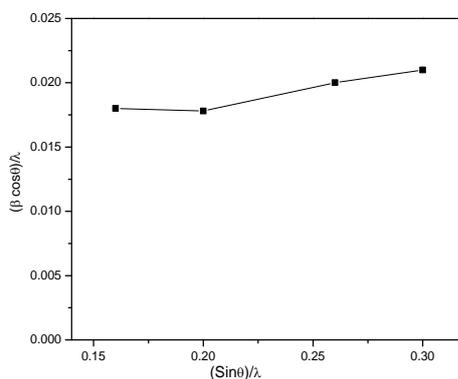
Figure-1 shows the XRD pattern of the PbS nanopowder. The spectrum showed various diffraction peaks at  $2\theta$  values of  $25.94^\circ, 30.24^\circ, 43.08^\circ, 51.05^\circ, 53.47^\circ, 62.56^\circ, 68.85^\circ, 70.96^\circ$  and  $78.93^\circ$ . The peaks were identified to originate from (111), (200), (220), (311), (222), (400), (331), (420) and (422) planes of bulk cubic zinc blende phase of PbS respectively. The information on strain and the particle size was obtained from the full widths at half maximum (FWHM) of the diffraction peaks. The FWHM ( $\beta$ ) can be expressed as a linear combination of the contributions from the strain ( $\epsilon$ ) and particle size ( $l$ ) through the following relation [3]:

$$\frac{\beta \cos \theta}{\lambda} = \frac{1}{L} + \frac{\epsilon \sin \theta}{\lambda} \tag{1}$$

Figure 2 represents the plot of  $\beta \cos \theta / \lambda$  vs.  $\sin \theta / \lambda$ . Slope of the graph gives the amount of strain which comes out to be  $4.34 \times 10^{-3}$  and the intercept on  $\beta \cos \theta / \lambda$  axis gives the particle size as  $\sim 10$  nm .



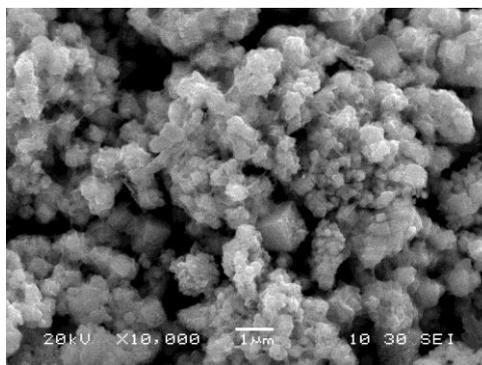
**Figure 1: XRD pattern of the PbS nanopowder**



**Figure 2: Plot to determine particle size and strain**

**Scanning electron microscopy:**

To assess the size and morphology of the PbS particles, we performed scanning electron microscopy (SEM). Fig.3 shows the SEM image of PbS nanocrystallites. It clearly shows an abundance of cube crystallites which have a mean particle size of  $\sim 70$  nm.

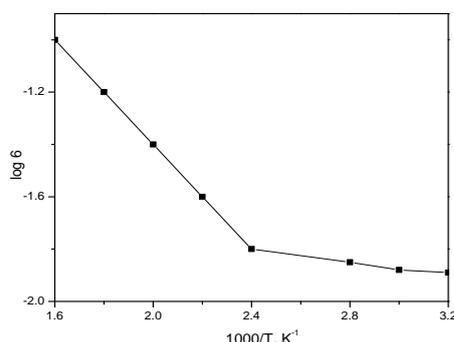


**Figure 3: SEM image of PbS nanocrystallites**

**Electrical properties**

The electrical conductivity of sol gel derived nanocrystalline PbS thin films was measured in the 300-500K temperature range using four probe techniques and its temperature dependence can be expressed by usual Arrhenous equation as:  
 $\sigma = \sigma_o \exp (-E_{a\sigma}/KT)$

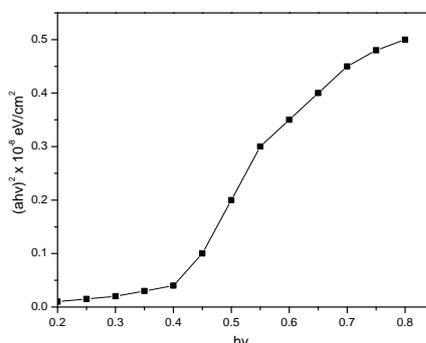
Where  $E_{ac}$  is the conductivity activation energy;  $T$ , the absolute temperature and  $K$ , the Boltzmann constant. The room temperature electrical resistivity of this sample is of the order of  $10^5 \Omega \text{cm}$ . The temperature dependence of an electrical conductivity is shown in Fig.4. Two distinct regions corresponding to two activation energies are clearly seen. The activation energies of an electrical conduction have been determined in both low and high temperature regions and are 0.45eV and 0.14 eV respectively.



**Figure 4: The temperature dependence of an electrical conductivity of PbS**

### Optical properties

The optical constants namely absorption coefficient ( $\alpha$ ), energy gap ( $E_g$ ) and type of the optical absorption spectrum in the 500-950 nm wavelength range at room temperature. The energy gap is determined from the studies for this deposited PbS material. Figure-5. Shows determination of the optical gap from the  $(\alpha h\nu)$  versus  $(h\nu)$  variation. A band gap of 0.41 eV has been determined for the as deposited PbS sample. The type of transition is band to band direct as determined from the  $\ln(\alpha h\nu)$  versus  $\ln(h\nu - E_g)$  variation.



**Figure 5: Plot of  $(\alpha h\nu)$  versus  $(h\nu)$  variation.**

### CONCLUSION

We conclude that nanocrystalline PbS films, reproducible both in the electrical and optical properties, can easily be obtained with almost negligible consumption of an electrical energy and the basic starting materials. The deposits are dark chocolate in color with a room temperature resistivity of  $10^5$  to  $10^6 \Omega \text{cm}$ . XRD studies showed cubic structure of PbS. The SEM observations revealed nanocrystalline crystalline nature of the film. The material exhibit high optical absorption coefficient ( $10^4/\text{cm}$ ) with a direct band gap type of transition. The estimated energy gap is 0.41 eV.

### ACKNOWLEDGEMENT

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### REFERENCES

- Brus L.E. (1994). *J. Chem. Phys.* **80**: 4403.
- Goldstein A. N., Echer C. M. and Alivisatos A. P. (1992). *Sci.* **356**: 1425.
- Qadri S.B., Skelton E.F., Hsu D., Dinsmore A.D., Yang J., Gray H.F. and Ratna B.R. (1999). *Phys. Rev. B.* **60**: 9191.
- Chen C.C., Herhold A.B., SJohnson C., Alivisatos A.P. (1997). *Sci.* **276**: 398.
- Bhargava R. N., Gallagher D., Hong H. and Nurmikko A. (1994). *Phys. Rev. Lett.* **72**: 416.
- Alivisatos A.P. (1998). *MRS Bull.* **25**: 18.
- Nanda J., Sapra S. and Sarma D. D. (2000). *Chem. Mater.* **12**: 1018.
- Bhattacharjee B., Ganguli D., Iakoubovski K., Stesmans A and Chaudhuri S. (2002). *MRS Bull.* **25**: 175.